

DIO59110H USB-Compliant Single-cell Li-Ion 1.5A Switching Charger

Features

- Fully Integrated, High-Efficiency Charger for Single-Cell Li-Ion and Li-Polymer Battery Packs
- Pin Selectable USB 500 mA Maximum Input Current Limit
- Charge Voltage Accuracy: ±0.5% (A:4.2V,B:4.3V,C:4.35V,D:4.4V)
- ±7% Input Current Regulation Accuracy
- ±7% Charge Current Regulation Accuracy
- 26V Absolute Maximum Input Voltage
- 6V Maximum Input Operating Voltage
- 1.5A Maximum Charge Rate
- 2MHz Synchronous Buck PWM Controller with Wide Duty Cycle Range
- Small Footprint 1µH External Inductor
- Dynamic Input Voltage Control
- Low Reverse Leakage to Prevent Battery Drain to VBUS
- Available in DFN3*3-12 Package.

Descriptions

The DIO59110H combines a highly integrated switch-mode charger, to minimize single-cell Lithium-ion (Li-ion) charging time from a USB power source.

The charger regulator circuits switch at 2MHz to minimize the size of external passive components.

The DIO59110H provides battery charging in three phases: conditioning, constant current and constant voltage.

The integrated circuit (IC) automatically restarts the charge cycle when the battery falls below an internal threshold. If the input source is removed, the IC enters a high-impedance mode, preventing leakage from the battery to the input. Charge current is reduced when the die temperature reaches at 120°C, protecting the device and PCB from damage.

Applications

- Cell Phones, Smart Phones, PDAs
- Tablet, Portable Media Players
- Gaming Device, Digital Cameras

Order Part Number	Top Marking		T _A	Package		
	59110X					
DIO59110HXCD12	YYWW	Green	-40 to 85°C	DFN3*3-12	Tape & Reel, 5000	
	。HXZ					

Ordering Information



Pin Assignments





Pin Definitions

Name	Description
NC	No connection.
NTC	Monitor battery temperature input connected to the battery NTC resistor.
DISABLE	Charging enable input, charging start when disable is low.
CTRL	CTRL=0, input current limit is 500mA. CTRL=1, input current is no limit.
STAT	Status. Open-drain output indicating charge status. The IC pulls this pin LOW when charging, and pulses STAT pin when fault.
BAT	Battery Voltage. Connect to the positive (+) terminal of the battery pack. Bypass with a 0.1µF capacitor to GND if the battery is connected through long leads.
CSIN	Charging current detection input terminal.
VBUS	Charger Input Voltage. Bypass with a 1µF capacitor to PGND.
PMID	Power Input Voltage. Power input to the charger regulator, bypass point for the input current sense, and high-voltage input switch. Bypass with a minimum of 4.7µF, 6.3V capacitor to PGND.
SW	Switching Node. Connect to output inductor.
GND	Ground.
Thermal Pad	Exposed pad beneath the IC for heat dissipation. Always solder thermal pad to the board, and have via on the thermal pad plane star-connecting to GND.



Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameter		Rating	Unit	
	Continuous	-1.4 to 26.0	V	
VBUS Voltage	Pulsed, 100ms Maximum Non-Repetitive	-2.0 to 26.0	v	
STAT Voltage		-0.3 to 26.0	V	
PMID Voltage		6.5	v	
SW, CSIN, VBAT, DISABLE Voltage		-0.3 to 6.5	v	
Voltage on Other Pins		-0.3 to 6.5	V	
Maximum V _{BUS} Slope above 5.5V when Charger are Active		4	V/µs	
ESD	НВМ	2000	V	
ESD	CDM	500	v	
Junction Temperature		-40 to 150	°C	
Storage Temperature		-65 to 150	°C	
Lead Soldering Temperature, 10 Seconds		260	°C	

Recommend Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended Operating conditions are specified to ensure optimal performance to the datasheet specifications. DIOO does not Recommend exceeding them or designing to Absolute Maximum Ratings.

Parameter		Rating	Unit
Supply Voltage		4 to 6	V
Negative VBUS Slew Rate during VBUS Short	T _A ≪60°C	4	Muo
Circuit, C _{MID} ≪4.7µF	T _A ≥60°C	2	V/µs
Ambient Temperature		-30 to 85	°C
Junction Temperature		-30 to 120	°C



Electrical Characteristics

 V_{IN} = 5V, T_A = 25°C, unless otherwise specified.

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Symbol	Parameter	Test Conditions	Min	Тур	Мах	Unit
Power Suppl	Power Supplies					
		V _{BUS} >V _{BUS(min)} , PWM Switching		10		mA
I _{VBUS}	VBUS Current	V _{BUS} > V _{BUS(min)} ; PWM Enabled, Not Switching (Battery OVP Condition)		0.2		mA
		DISABLE=1		96		μA
I _{LKG}	VBAT to VBUS Leakage Current	t 0°C <t<sub>J<85°C, V_{BAT}=4.2V,V_{BUS}=0V</t<sub>		1.6	5.0	μA
I _{BAT}	Battery is charge Current in High- Impedance Mode	DISABLE=1, 0°C <t<sub>J<85°C, V_{BAT}=4.2V</t<sub>		12	20	
Charger Vol	Itage Regulation					
	Charge Voltage Range		4.2		4.4	
V _{OREG}	Charge Veltage Assures	T _A =25°C	-0.5%		0.5%	V
	Charge Voltage Accuracy	T _J =0 to 125°C	-1%		1%	
Charging Cu	Charging Current Regulation					
	Output Charge Current Range	I _{OCHRG} =101.9mV/ R _{SENSE}		1498		mA
I _{OCHRG}	Charge Current Accuracy Across R _{SENSE}		-7		7	%
Logic Level	s: DISABLE, SDA, SCL					•
V _{IH}	High-Level Input Voltage		1.05			V
VIL	Low-Level Input Voltage				0.4	V
l _{iN}	Input Bias Current	Input=5V		5.0		μA
Charge Terr	mination Detection					
	Termination Current Range	I _(TERM) =9.38mV/ R _{SENSE}		138		mA
I _(TERM)	Termination Current Accuracy	R _{SENSE} =68mΩ	-25		25	%
	Termination Current Deglitch Time			30		ms
Input Power	r Source Detection					
	VBUS Input Voltage Rising	To Initiate and Pass VBUS Validation	3.75	4	4.25	V
V _{hys}				0.3	L	V
t _{VBUS_VALID}	VBUS Validation Time			30		ms
Special Cha	n rger (V BUS)					
V _{SP}	Special Charger VBUS Voltage			4.525		V
			<u> </u>			



		DI059110H					
	Special Charger Set point		-4		4	%	
	Accuracy		-7		-	70	
Input Current Limit							
	Input Current Limit Threshold	CTRL=0	470	500	530	mA	
IINLIM		CTRL=1		No limit		mA	
Battery Rec	harge Threshold						
N	Recharge Threshold	Below V _(OREG)		200		mV	
Vrch	Deglitch Time	V _{BAT} Falling Below V _{RCH} Threshold		30		ms	
STAT Outpu	ıt						
V _{STAT(OL)}	STAT Output Low	I _{STAT} =10mA			0.4	V	
I _{STAT(OH)}	STAT High Leakage Current	V _{STAT} =5V			1	μA	
Sleep Comp	parator						
V _{SLP}	Sleep-Mode Entry Threshold, V _{BUS} V _{BAT}	$4V \leqslant V_{BAT} \leqslant V_{OREG}, V_{BUS}$ Falling	0	0.04	0.1	V	
V _{SLP-EXIT}	Sleep-Mode Exit Threshold, VBUS- VBAT			0.1		V	
t _{SLP_EXIT}	Deglitch Time for VBUS Rising Above V_{BAT} by V_{SLP}	Rising Voltage		30		ms	
Power Swite							
	Q3 On Resistance(VBUS to PMID)	I _{IN(LIMIT)} =500mA		86			
R _{DS(ON)}	Q1 On Resistance(PMID to SW)			85		mΩ	
	Q2 On Resistance(SW to GND)			75			
Charger PW	/M Modulator						
fsw	Oscillator Frequency		1.7	2	2.3	MHz	
D _{MAX}	Maximum Duty Cycle				100	%	
D _{MIN}	Minimum Duty Cycle			6		%	
I _{SYNC}	Synchronous to Non-Synchronous Current Cut-Off Threshold	Low-Side MOSFET(Q2) Cycle-by- Cycle Current Limit		300		mA	
Battery Det	ection			1			
IDETECT	Battery Detection Sink Current	Begins after Charge Termination Detected		10		mA	
t _{DETECT}	Battery Detection Time			30		ms	
Protection a	and Timers	1	1	1	L	L	
	VBUS Over-Voltage Shutdown	V _{BUS} Rising	5.82	6	6.2	V	
VBUS _{OVP}	Hysteresis	V _{BUS} Falling		200		mV	
	-		1	1	<u> </u>		



I _{LIMPK(CHG)}	Q1 Cycle-by-Cycle Peak Current Limit	Charge Mode		3		А
N	Battery Short-Circuit Threshold	V _{BAT} Rising	1.95	2	2.05	V
V _{SHORT}	Hysteresis	V _{BAT} Falling		100		mV
I _{SHORT}	Linear Charging Current	V _{BAT} <v<sub>SHORT</v<sub>	20	30	40	mA
- T	Thermal Shutdown Threshold	TJ Rising		145		°C
T _{SHUTDWN}	Hysteresis	T _J Falling		10		°C
T _{CF}	Thermal Regulation Threshold	Charge Current Reduction Begins		120		°C
t _{INT}	Detection Interval			30		ms
NTC						
T _{DET_RANGE}	Detected temperature range	R _{NTC} =10 KΩ	0		50	°C
V _{NTC_HOT}	High temperature detection voltage threshold	Battery temperature rise		0.12		V
	High temperature detection voltage hysteresis	Battery temperature drop		40		mV
V _{NTC_COLD}	Low temperature detection voltage threshold	Battery temperature drop		0.9		V
	Low temperature detection voltage hysteresis	Battery temperature rise		60		mV

Notes:

1. Negative current is current flowing from the battery to VBUS (discharging the battery).







Application Information

Circuit Description/Overview

When charging batteries with a current-limited input source, such as USB, a switching charger's high efficiency over a wide range of output voltages minimizes charging time.

DIO59110H combines a highly integrated synchronous buck regulator for charging. The regulator employs synchronous rectification for charger regulators to maintain high efficiency over a wide range of battery voltages and charge states.

The DIO59110H has three operating modes:

- 1. Charge Mode: Charge a signal-cell Li-ion or Li-polymer battery.
- 2. High-Impedance Mode:

The charging circuits are OFF in this mode. Current flow from VBUS to the battery or from the battery to VBUS is blocked in this mode. This mode consumers very little current from VBUS or the battery.

Charge Mode

In charge Mode, DIO59110H employs four regulation loops:

- 1. Input Current: Limits the amount of current drawn from VBUS. This current is sensed internally and can be set by CTRL pin.
- 2. Charging Current: Limits the maximum charging current. This current is sensed using an external R_{SENSE} resistor.
- 3. Charge Voltage: The regulator is restricted from exceeding this voltage. As the internal battery voltage roses, the battery's internal impedance and R_{SENSE} work in conjunction with the charge voltage regulation to decrease the amount of current flowing to the battery. Battery charging is completed when the voltage across R_{SENSE} drops below the I_{TERM} threshold.
- 4. Temperature: If the IC's junction temperature reaches 120℃,charge current is reduced until the IC's temperature stabilizes at 120℃.
- An additional loop limits the amount of drop on VBUS to a voltage (V_{SP}) to accommodate "special chargers" that limit current to a lower current than might be available from a "normal" USB wall charger.

Battery Charging Curve

If the battery voltage is below V_{SHORT} , a linear current source pre-charges the battery until V_{BAT} reaches V_{SHORT} . The PWM charging circuit is then started and the battery is charged with a constant current if sufficient input power is available. The current slew rate is limited to prevent overshoot.

The DIO59110H is designed to work with a current-limited input source at VBUS. During the current regulation phase of charging, I_{INLIM} limits the current available to charge the battery and power the system. The effect of I_{INLIM} on I_{CHARGE} can be see in Figure 5.



<u>DIO59110H</u>







Figure 5. Charge Curve, IINLIM Limits ICHARGE

Assuming that V_{OREG} is programmed to the cell's fully charged "float" voltage, the current that the battery accepts with the PWM regulator limiting its output (sensed at VBAT) to V_{OREG} declines, and the charger enters the voltage regulation phase of charging. When the current declines to I_{TERM} value, the charge cycle is complete.

A new charge cycle begins when one of the following occurs:

- The battery voltage falls below Voreg-VRCH
- VBUS Power on Reset (POR) clears and the battery voltage is below the V_{SHORT}.
- Reset DISABLE pin and battery voltage is below VOREG-VRCH

PWM Controller in Charge Mode

The IC uses a current-mode PWM controller to regulator the output voltage and battery charge currents. The synchronous rectifier (Q2) has a current limit that which off the FET when the current is negative by more than 400mA peak. This prevents current flow from battery.

VBUS POR/Non-Compliant Charger Rejection

When the IC detects that VBUS has risen above $V_{IN(MIN)}$ (4.3V), the IC applies a 250 Ω load from VBUS to GND. To clear the VBUS POR (Power-On-Reset) and begin charging, VBUS must remain above $V_{IN(MIN)}$ and below VBUS_{OVP} for t_{VBUS_VALID} (30ms) before the IC initiates Charging. The VBUS validation sequence always occurs



charging is initiated or re-initiated (for example, after a VBUS OVP fault or a V_{RCH} recharge initiation). t_{VBUS_VALID} ensures that unfiltered 50/60Hz chargers and other non-compliant chargers are rejected.

Special Charger

The DIO59110H has additional functionality to limit input current in case a current-limited "special charger" is supplying VBUS. These slowly increase the charging current until either.

- INLIM OF IOCHARGE is reached
- or

■ V_{BUS}=V_{SP}.

If V_{BUS} collapses to V_{SP} when the current is ramping up, the DIO59110H charge with an input current that keeps $V_{BUS}=V_{SP}$.

Thermal Regulation and Protection

When the IC's junction temperature reaches T_{CF} (about 120°C), the charger reduces its output current to 550mA to prevent overheating. If the temperature increases beyond $T_{SHUTDOWN}$; charging is suspended, and STAT is pulsed HIGH. In Suspend Mode, all timers stop and the state of the IC's logic is preserved. Charging resumes after the die cools to about 120°C.

Charge Mode Input Supply Protection

Sleep Mode

When V_{BUS} falls below $V_{BAT}+V_{SLP}$, and V_{BUS} is above $V_{IN(MIN)}$. the IC enters Sleep Mode to prevent the battery from draining into VBUS. During Sleep Mode, reverse current is disabled by body switching Q1.

Input Supply Low-Voltage Detection

The IC continuously monitors VBUS during charging. If V_{BUS} falls below V_{IN(MIN)}, the IC:

- 1. Terminates charging.
- 2. Pulses the STAT pin. .

If V_{BUS} recovers above the $V_{\text{IN(MIN)}}$ rising threshold after time 30ms, the charging process is repeated. This function prevents the USB power bus from collapsing or oscillating when the IC is connected to a suspended USB port.

Input Over-Voltage Detection

When the V_{BUS} exceeds VBUS_{OVP}, the IC:

- 1. Turns off Q3
- 2. Suspends charging
- 3. Pulses the STAT pin.

When V_{BUS} falls about 150mV below VBUS_{OVP}, the fault is cleared and charging resumes after V_{BUS} is revalidated (see VBUS POR/Non-Compliant Charger Rejection).

Charge Mode Battery Detection & Protection

VBAT Over-Voltage Protection

The OREG voltage regulation loop prevents V_{BAT} from overshooting the OREG voltage when the battery is removed. When the PWM charger runs a voltage higher than 4.8V, PWM pulses stop and pulses the STAT pin.

Battery Detection During Charging

The IC can detect the presence, absence, or removal of a battery. During normal charging, once VBAT is close to



VOREG and the termination charge current is detected, the IC terminates charging and turns on a discharge current, IDETECT, for 30ms. If VBAT is still above 2V, the battery is present. If VBAT is below 2V, the battery is absent and IC enter No Battery Mode.

Battery Short-Circuit Protection

If the battery voltage is below the short-circuit threshold (V_{SHORT}); a linear current source, I_{SHORT}, supplies V_{BAT} until V_{BAT}>V_{SHORT}.

NTC protection

NTC pin output 30uA current to NTC resistor ($10k\Omega$). When battery temperature rises to $50^{\circ}C(V_{NTC}=120mV)$ or falls to $0^{\circ}C(V_{NTC}=0.9V)$, the IC stops charging, and IC pulses the STAT pin. If NTC protection is not used, NTC pin must connect to $10k\Omega$ normal resistor to ground.

System Operation with No Battery

The DIO59110H continues charging after VBUS POR with the default parameters, regulating the V_{BAT} line to 3.78V. In this way, the DIO59110H can start the system without a battery. Re-connect power to VBUS or reset DISABLE pin, IC can exit No Battery Mode.

Charger Status/Fault Status

The STAT pin indicates the operating condition of the IC and provides a fault indicator for interrupt driven systems.

EN_STAT	Charge State	STAT Pin			
х	No Charging	OPEN			
1	Charging	LOW			
х	Fault	2Hz Pulse			

Table 1. STAT Pin Function

The type of fault in Charge Mode (see Table 2).

Table 2. Fault Status During Charge Mode

Fault Description	
VBUS OVP	
Sleep Mode	
Poor Input Source	
Battery OVP	
Thermal Shutdown	
No Battery	
NTC protection	
	VBUS OVP Sleep Mode Poor Input Source Battery OVP Thermal Shutdown No Battery

PCB Layout Recommendations

Bypass capacitors should be placed as close to the IC as possible. In particular, the total loop length for CMID should be minimized to reduce overshoot and ringing on the SW, PMID, and VBUS pins. All power and ground pins must be routed to their bypass capacitors, using top copper whenever possible. Copper area connecting to the IC should be maximized to improve thermal performance if possible.



CONTACT US

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